



High-Speed USB2.0 1:2 Multiplexer/DeMultiplexer Switch with Signal Enable

Features

- → V_{DD} Operation at 2.5 V and 3.3 V
- → V_{I/O} Accepts Signals up to 5.5 V
- → 1.8-V Compatible Control-Pin Inputs
- \rightarrow Low-Power Mode When \overline{OE} Is Disabled (2 μ A)
- \rightarrow r_{ON} = 6 Ω Maximum
- \rightarrow $\Delta r_{ON} = 0.2\Omega$ Typical
- \rightarrow Cio(on) = 4pF Typical
- → Support Over Voltage Protection
- → Low Power Consumption (50 µA Maximum)
- **→** ESD Performance
 - · IO Pins
 - 12KV HBM
 - 1KV CDM
 - +/-8KV contact Discharge (IEC61000-4-2)
 - VDD, GND, S, OE Pins
 - 4KV HBM
 - 1KV CDM
- → High Bandwidth (1.6 GHz Typical)
- → Packaging (Pb-free & Green):
 - 10-contact, UDFN (ZW10)
 - 10-contact, UQFN (ZUA10)

Description

The PI3USB221E is a high-bandwidth switch specially designed for the switching of high-speed USB 2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The wide bandwidth (1.1 GHz) of this switch allows signals to pass with minimum edge and phase distortion. The device multiplexes differential outputs from a USB host device to one of two corresponding outputs. The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs.

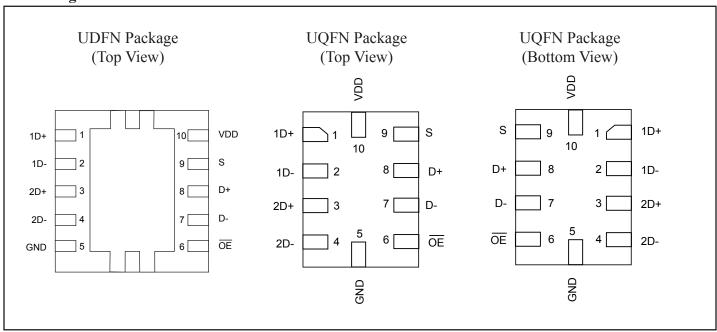
It is designed for low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480 Mbps).

The PI3USB221E offer over voltage protection for the D+/D-pins as per the USB 2.0 specification. with the chip power on or off if D+/D- pins are shorted to VBus (5V+/-5%), a less than 3.8V (typical) signal will transmit through 1D+/1D- and 2D+/2D-output.

Applications

- Routes Signals for USB 1.0, 1.1, and 2.0
- Mobile Industry Processor Interface (MIPI) Signal Routing

Pin Configuration

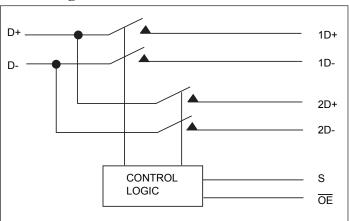


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Block Diagram



Pin Description

Name	Description
ŌE	Active LOW, Output enable
S	Select input
D	COM port
nD	I/O for USB data path (port 1 and port 2)

Truth Table

S	OE	Function
X	Н	Disconnect
L	L	D = 1D
Н	L	D = 2D

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PI3USB221E

Absolute Maximum Ratings(1)

Over operating free-air temperature range (unless otherwise noted)

1 0 1 0 0	
V _{DD} Supply Voltage Range	0.5V to 4.6V
V _{IN} Control Input Voltage Range ^(2, 3)	
V _{I/O} Switch I/O Voltage Range ^(2, 3, 4)	0.5 V to 5.5 V
$I_{IK} \ Control \ Input \ Clamp \ Current \ (V_{IN} < 0)$	50mA
$I_{I/OK}$ I/O Port Clamp Current ($V_{I/O}$ < 0)	50mA
I _{I/O} ON-state Switch Current ⁽⁵⁾	±120mA
Continuous Current through V_{DD} or GND θ_{JA} Package Thermal Impedance	±100mA
TLLGA Package	48.7°C/W
TDFN Package	243°C/W
T _{stg} Storage Temperature Range	65 to 150°C
Tj Junction Temperature	125°C

Notes:

- 1. Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. All voltages are with respect to ground, unless otherwise specified.
- 3. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 4. VI and VO are used to denote specific conditions for VI/O.
- 5. II and IO are used to denote specific conditions for II/O.
- 6. The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions(1)

Symbol	Description	Parameter	Min.	Max.	Unit
V_{DD}	Supply voltage		2.3	3.6	
V _{IH} I	High-level control input voltage	$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$	1.3	-	V
		$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	1.4	-	
V _{IL} L	Low-level control input voltage	$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$		0.6	V
		$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$		0.6	
V _{I/O}	Data input/output voltage		0	4.6	
T _A	Operating free-air temperature		-40	85	°C

Note:

1. All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation.





Electrical Chatacteristics

Over operating free-air temperature range (unless otherwise noted)

Parameter		Testing Conditions		Min.	Тур.	Max.	Unit
V _{IK}		$V_{DD} = 3.6V, 2.7V, I_I = -18 \text{ mA}$				-1.2	V
I _{IN}	Control Inputs	$V_{DD} = 3.6V, 2.7V, 0V, V_{IN} = 0V \text{ to } 3.6V$				±1	
$I_{OZ}^{(3)}$		$V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} \text{ or GN}$ $V_{O} = 0V \text{ to } 3.6V, V_{I} = 0V, \text{ Switch O}$				±1	
т		V - 0V	$V_{I/O} = 0V \text{ to } 3.6V$			±2	
$I_{(OFF)}$		$V_{DD} = 0V$	$V_{I/O} = 0$ to 2.7V			±1	
I _{CC}		V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} or GN $I_{I/O}$ = 0 V, Switch ON or OFF	ND,		25	50	μΑ
I _{CC} (low mode)	power	$V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD}$ or GND, Switch disabled, (\overline{OE} in high state)				4	
1)1cc(4)	Control		$V_{DD} = 2.7V$, S sweeps from 1.4V to 3.3V, OE/ = 0V			15	
	Inputs		$V_{DD} = 2.7V$, OE/ sweeps from 1.4V to 3.3V, S = 0V			0.75	
C _{IN}	Control Inputs	$V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V$			1	2	_
C _{io(OFF)}		$V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V, \text{ Switch OFF}$			2	3	pF
C _{io(ON)}		$V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V \text{ or } 0V, \text{ Switch ON}$			4	6	
ron ⁽⁵⁾		$V_{DD} = 3V, 2.3V$	$V_I = 0V, I_O = 30 \text{ mA}$			4	
ION		VDD - 3 V, 2.3 V	$V_I = 2.4V$, $I_O = -15 \text{ mA}$			6	
Dr _{ON} ⁽⁶⁾		$V_{DD} = 3V, 2.3V$	$V_{\rm I} = 0V, I_{\rm O} = 30 \text{ mA}$		0.2		Ω
		v DD - 3 v, 2.3 v	$V_I = 1.7V$, $I_O = -15 \text{ mA}$		0.2		
**		$V_{DD} = 3V, 2.3V$	$V_I = 0V, I_O = 30 \text{ mA}$		1		
r _{ON(flat)}		ν _{DD} = 3 ν, 2.3 ν	$V_I = 1.7V$, $I_O = -15 \text{ mA}$		1		
$V_{\text{pass}} \qquad V_{\text{DD}} = 2.5 - 3.3 V$		$V_{DD} = 2.5 - 3.3V$	$V_{IN} > 3.8V$, $I_{O} = 10uA$	2.8	3.8	4.2	V

Notes:

- 1. V_{IN} and I_{IN} refer to control inputs. VI, VO, II, and IO refer to data pins.
- All typical values are at $V_{DD} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}\text{C}$.
- 3. For I/O ports, the parameter IOZ includes the input leakage current.
- 4. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{DD} or GND.
- 5. Measured by the voltage drop between the input and output terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two terminals.
- 6. Dron is delta Ron between channels

Dynamic Electrical Chatacteristics

Over operating range, $T_A = -40$ °C to 85°C, $V_{DD} = 3.3 \text{ V} \pm 10\%$, GND = 0V

Symbol	Parameter	Test Conditions	Typ.(1)	Unit
X _{TALK}	Crosstalk	$R_L = 50\Omega, f = 250 \text{ MHz}$	-40	dr.
O _{IRR}	OFF isolation	$R_{L} = 50\Omega, f = 250 \text{ MHz}$	-41	dB
BW	Bandwidth (-3 dB)	$R_{\rm L} = 50\Omega$	1.6	GHz

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1. For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.

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PI3USB221E

Switching Chatacteristics

Over operating range, $T_A = -40$ °C to 85°C, $V_{DD} = 3.3 \text{ V} \pm 10\%$, GND = 0V

Symbol	Parameter		Min.	Typ.(1)	Max.	Unit
t _{pd}	Propagation Delay	(2,3)		0.25		
4		S to D, nD			125	
t _{ON} Line enable time	OE to D, nD			100		
t _{OFF} Line disable time	S to D, nD			12	ns	
	OE to D, nD			12	115	
t _{SK(O)}	Output skew between center port to any other port ⁽²⁾			0.1	0.2	
t _{SK(P)}	Skew between opposite transitions of the same output (tPHL – tPLH) ⁽²⁾			0.1	0.2	
t _{VPASS}	OVP response time			53		ns

Notes:

- 1. For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Specified by design

^{3.} The switch contributes no propagational delay other than the RC delay of the on resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 10-pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.





Application Information

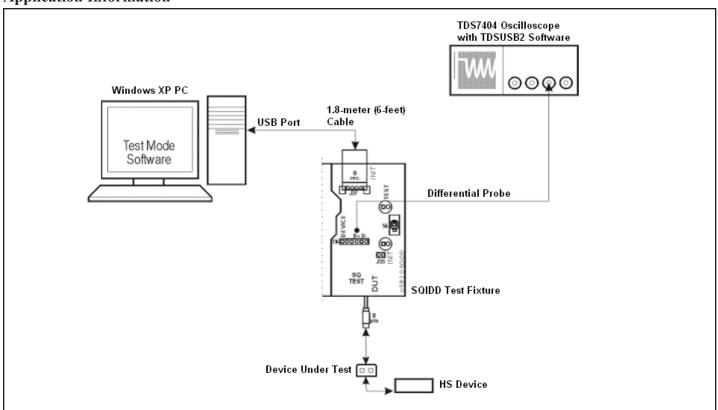
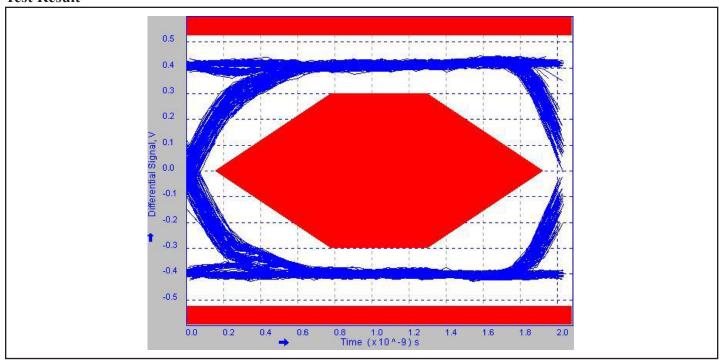


Figure 1: HS Eye Test Setup

Test Result

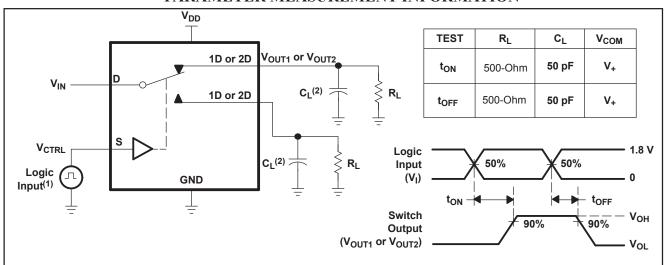


Test Result: High-speed, Up-stream, Near-end Eye of PI3USB221E





PARAMETER MEASUREMENT INFORMATION



- (1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50-Ohm, t_f<5 ns, t_f<5 ns.
- $^{(2)}$ C_L includes probe and jig capacitance.

Figure 2. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

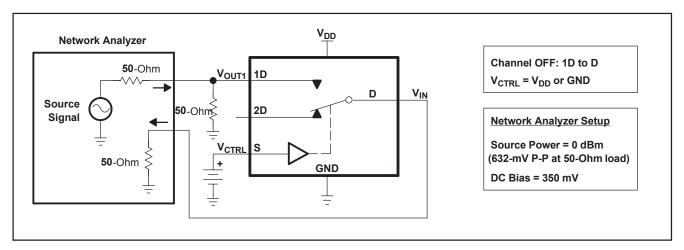


Figure 3.OFF Isolation (O_{ISO})



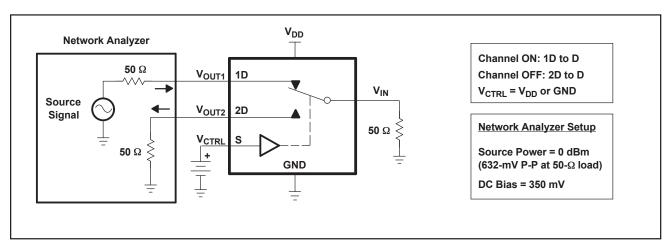


Figure 4. Crosstalk (X_{TALK})

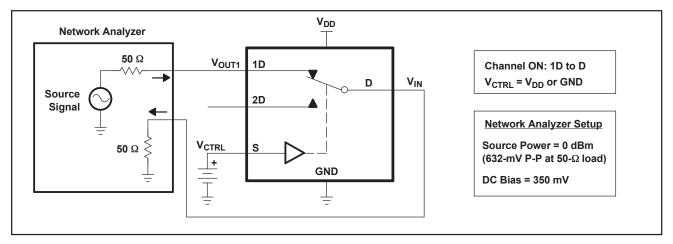


Figure 5. Bandwidth (BW)

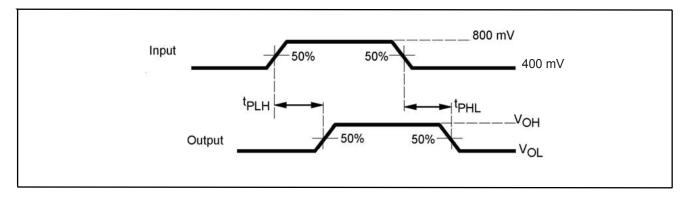


Figure 6. Propagation Delay



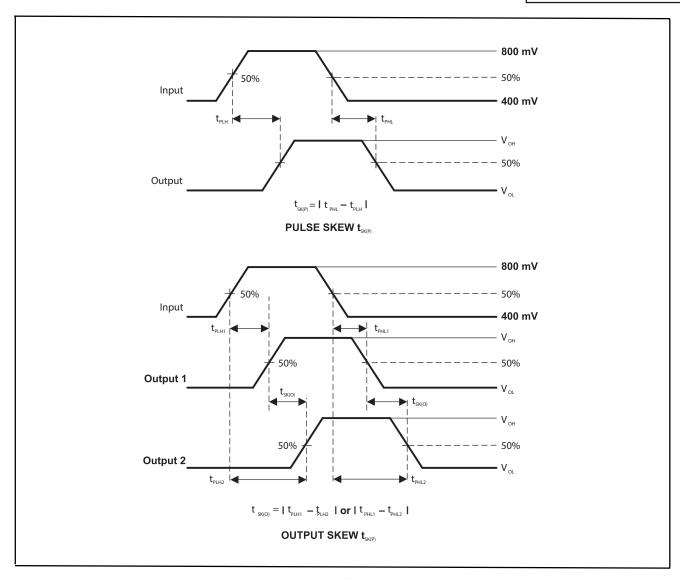


Figure 7. Skew Test

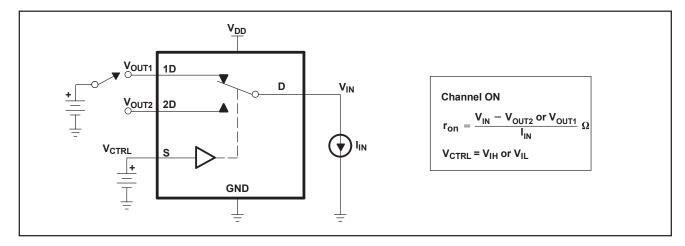


Figure 8. ON-State Resistance (ron)





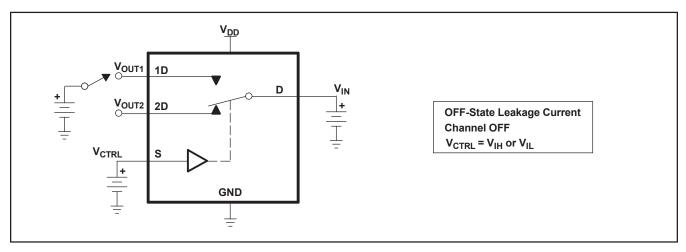


Figure 9. OFF-State Leakage Current

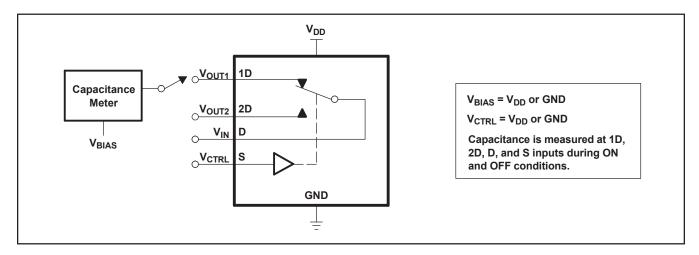
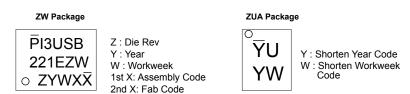


Figure 10. Capacitance

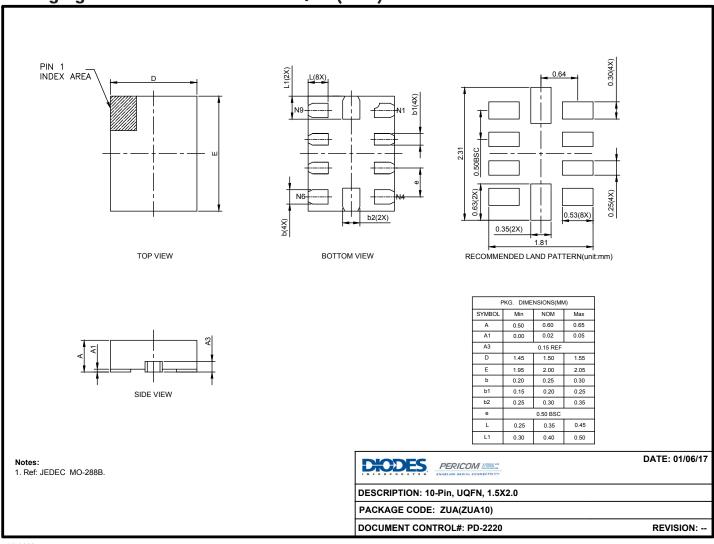
Part Marking Information







Packaging Mechanical: 10-contact UQFN (ZUA)

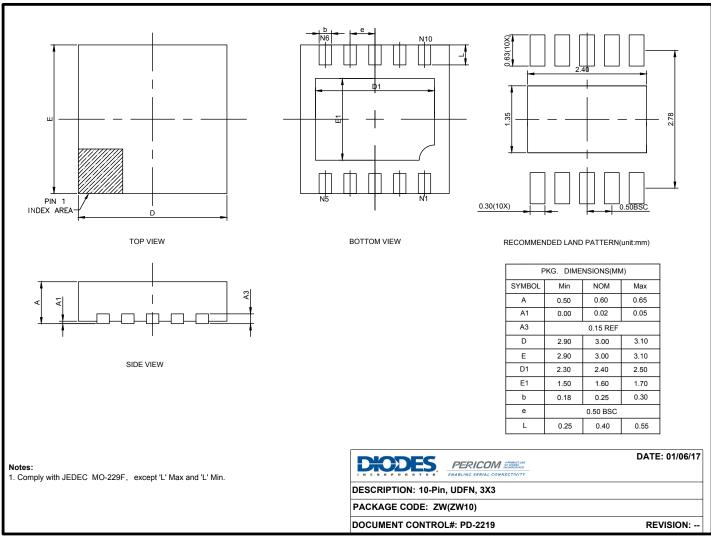


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Packaging Mechanical: 10-contact UDFN (ZW)



17-0001

For latest package info.

 $please\ check:\ http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/packaging-mechanical-and-thermal-characteristics/packaging-mech$

Ordering Information

Ordering Number	Package Code	Package Description
PI3USB221EZUAEX	ZUA	10-Pin, 1.5x2.0 (UQFN), Tape & Reel
PI3USB221EZWEX	ZW	10-Pin, 3x3 (UDFN), Tape & Reel

Notes:

- Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel

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PI3USB221E

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